

Schottky Diode

V_{RRM} = 45 V
 I_{FAV} = 2x 30 A
 V_F = 0.67 V

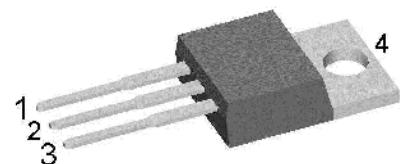
High Performance Schottky Diode

Low Loss and Soft Recovery

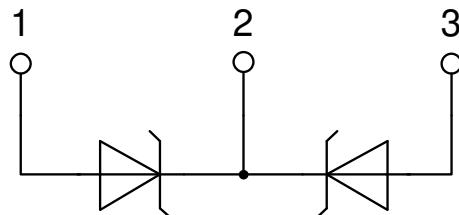
Common Cathode

Part number

DSA60C45PB



Backside: cathode



Features / Advantages:

- Very low V_F
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

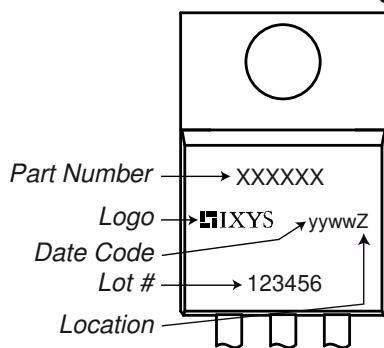
Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.

Schottky

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
V_{RSM}	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			45	V
V_{RRM}	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ\text{C}$			45	V
I_R	reverse current, drain current	$V_R = 45 \text{ V}$ $V_R = 45 \text{ V}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		450 5	μA mA
V_F	forward voltage drop	$I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$ $I_F = 30 \text{ A}$ $I_F = 60 \text{ A}$	$T_{VJ} = 25^\circ\text{C}$ $T_{VJ} = 125^\circ\text{C}$		0.79 0.99 0.67 0.88	V V
I_{FAV}	average forward current	$T_C = 155^\circ\text{C}$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ\text{C}$		30	A
V_{F0} r_F	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ\text{C}$		0.42 6.6	V $\text{m}\Omega$
R_{thJC}	thermal resistance junction to case				0.85	K/W
R_{thCH}	thermal resistance case to heatsink			0.5		K/W
P_{tot}	total power dissipation		$T_C = 25^\circ\text{C}$		175	W
I_{FSM}	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 \text{ V}$	$T_{VJ} = 45^\circ\text{C}$		490	A
C_J	junction capacitance	$V_R = 5 \text{ V}$ f = 1 MHz	$T_{VJ} = 25^\circ\text{C}$		980	pF

Package TO-220

Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal ¹⁾			35	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				2		g
M_d	mounting torque		0.4		0.6	Nm
F_c	mounting force with clip		20		60	N

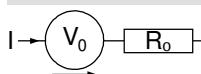
Product Marking

Part description

D = Diode
S = Schottky Diode
A = low VF
60 = Current Rating [A]
C = Common Cathode
45 = Reverse Voltage [V]
PB = TO-220AB (3)

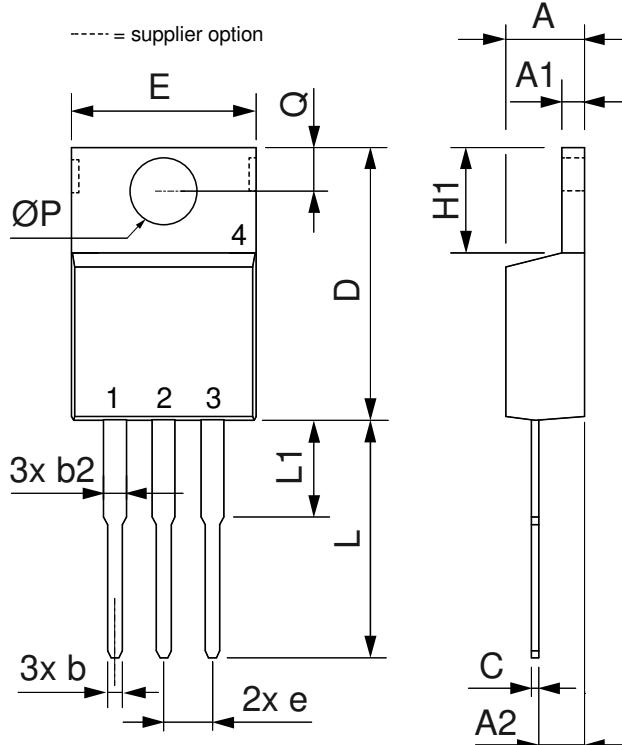
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA60C45PB	DSA60C45PB	Tube	50	505556

Similar Part	Package	Voltage class
DSA60C45HB	TO-247AD (3)	45

Equivalent Circuits for Simulation
^{*}on die level

 $T_{VJ} = 175^\circ\text{C}$

Schottky

$V_{0\ max}$	threshold voltage	0.42	V
$R_{0\ max}$	slope resistance *	3.4	

Outlines TO-220


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125

